



# R-C Thermal Model Parameters

## DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/tank and Cauer/filter configurations are included. When implemented in PSpice, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the PSpice simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in application note AN609, "Thermal Simulation of Power MOSFETs on the PSpice Platform".

## R-C THERMAL MODEL FOR TANK CONFIGURATION



R-C VALUES FOR TANK CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RT1	12.7762	78.1251m	n/a
RT2	3.1049	251.0297m	n/a
RT3	335m	5.9246m	n/a
RT4	23.7839	264.9206m	n/a
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	8.6430	12.9661m	n/a
CT2	609.9830m	27.3042m	n/a
CT3	5.6209m	1.7474m	n/a
CT4	3.5862	120.5827m	n/a

### Note

- n/a indicates not applicable

This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.



R-C THERMAL MODEL FOR FILTER CONFIGURATION



R-C VALUES FOR FILTER CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RF1	816.3000m	4.8399m	n/a
RF2	4.5831	146.8583m	n/a
RF3	21.2757	269.3885m	n/a
RF4	13.3249	177.1833m	n/a
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CF1	12.8066m	888.9908u	n/a
CF2	682.6968m	6.8362m	n/a
CF3	1.7099	14.2282m	n/a
CF4	1.9630	143.2945m	n/a

Note

- n/a indicates not applicable

